

# **Eight-channel Darlington Drivers**

#### **FEATURES**

Improved replacement for the ULN2803 Fast turn-on and turn-off. TTL/CMOS compatible.

### **APPLICATIONS**

- · Stepping Motor Driver.
- Relay Driver.
- LED Driver.
- Solenoid Driver.

#### DESCRIPTION

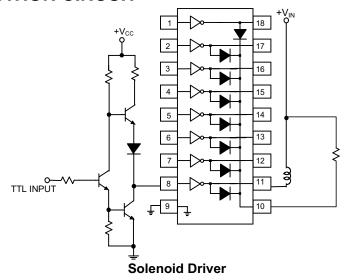
Manufactured with the standard bipolar process, the SS62803 is a high-voltage, high-current 8-channel Darlington array, with each of the output transistors capable of sinking peak load current of 500mA and capable of withstanding at least 50V in the OFF state.

The SS62803 has a 2.7K $\Omega$  series base resistor to each Darlington pair and thus allows operation directly with TTL or CMOS logic circuitry operating at a supply voltage of 5V. Outputs of the drivers can be paralleled for higher load current capability. These make the SS62803 ideally suited for numerous interfaces between low-level logic circuitry and high-power peripheral loads, particularly those beyond the capabilities of standard logic buffers. Typical loads include relays, solenoids, stepping multiplexed motors, heaters, LED, incandescent displays.

The SS62803 features open collector outputs and integral diodes for inductive load transient suppression.

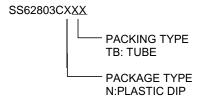


## TYPICAL APPLICATION CIRCUIT



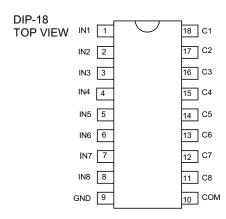
### ORDERING INFORMATION

## **PIN CONFIGURATION**



Example: SS62803CNTB

→ in DIP-18 Package & Tube Packing Type



## ABSOLUTE MAXIMUM RATINGS (TA=25°C)

Output Voltage		50V			
Input Voltage		30V			
Continuous Collector Current500m.					
Continuous Base Current					
Power Dissipation,	(One Darlington Pair)	1.0W			
	(Total Package)	2.25W			
Operating Ambient Temperature Range		-20°C~ 85°C			
Storage Temperatur	e Range	-65°C~ 150°C			



# **ELECTRICAL CHARACTERISTICS**

( $T_A$ =25°C, unless otherwise specified.)

PARAMETERS	TEST CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Output Leakage Current	V <sub>CE</sub> =50V,T <sub>A</sub> =25°C V <sub>CE</sub> =50V,T <sub>A</sub> =70°C, Fig. 1	I <sub>CEX</sub>			30 100	μΑ
Collector-Emitter Saturation Voltage	$I_{C}$ =100mA, $I_{B}$ =250μA $I_{C}$ =200mA, $I_{B}$ =350μA $I_{C}$ =350mA, $I_{B}$ =500μA , Fig. 2	VCE(SAT)		0.8 0.9 1.0	1.1 1.3 1.5	V
Input Current	V <sub>IN</sub> =3.85V, Fig. 3 I <sub>C</sub> =500μA,T <sub>A</sub> =70°C, Fig. 4	I <sub>IN(ON)</sub>	50	0.93 65	1.35	mA μA
Input voltage	V <sub>CE</sub> =2.0V, I <sub>C</sub> =200mA V <sub>CE</sub> =2.0V, I <sub>C</sub> =250mA V <sub>CE</sub> =2.0V, I <sub>C</sub> =300mA, Fig. 5	V <sub>IN(ON)</sub>			2.3 2.4 2.5	V
Input Capacitance		C <sub>IN</sub>		15	25	pF
Clamp Diode Leakage Current	V <sub>R</sub> =50V, T <sub>A</sub> =25°C V <sub>R</sub> =50V, T <sub>A</sub> =70°C, Fig. 6	I <sub>R</sub>			30 100	μΑ
Clamp Diode Forward Voltage	I <sub>F</sub> =350mA Fig. 7	V <sub>F</sub>		1.4	1.8	V
Turn-On Delay	0.5 V <sub>IN</sub> to 0.5 V <sub>OUT</sub> , Fig. 8	T <sub>ON</sub>		0.1	0.5	μS
Turn-off Delay	0.5 V <sub>IN</sub> to 0.5 V <sub>OUT</sub> , Fig. 8	TOFF		0.2	8.0	μS



# **TEST CIRCUITS**

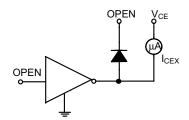
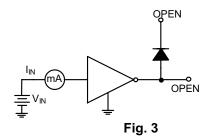
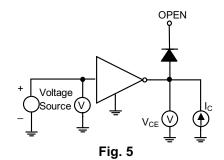
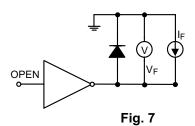


Fig. 1







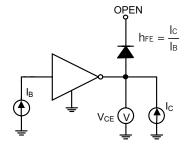


Fig. 2

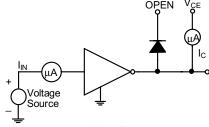
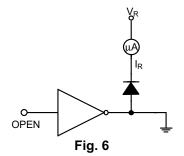


Fig. 4





# TEST CIRCUITS (Continued)

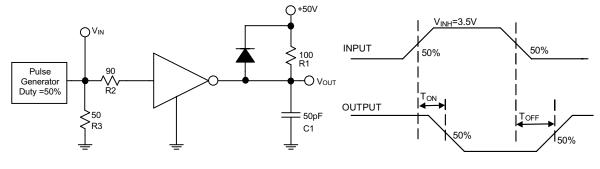


Fig. 8

Fig. 9 Test Circuit of Fig. 8

## **PIN DESCRIPTIONS**

PIN 1~8: IN1~IN8 - Control signal input pin.

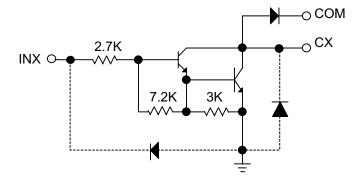
PIN 9: GND - Power ground.

PIN 10: COM - The output pin (Cathode) of freewheeling diode.

PIN 11~18: C1~C8 - Each of the pins may individually sink load current from some controlled circuits. The

sunk current should be under 500mA in a continuous mode.

## **DRIVER CIRCUIT**





## SWITCHING DELAY

# ALLOWABLE AVERAGE POWER DISSIPATION

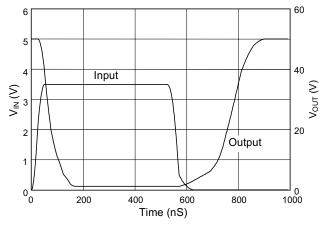


Fig. 10 Switching Delay

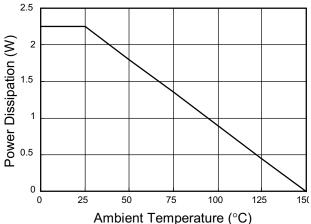
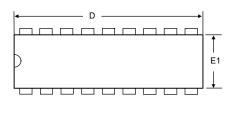
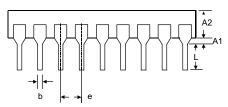


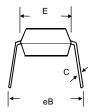
Fig. 11 Power Dissipation vs. Ambient Temperature

#### PHYSICAL DIMENSIONS

18 LEAD PLASTIC DIP (unit: mm)







SYMBOL	MIN	MAX		
A1	0.381	_		
A2	2.92	4.96		
b	0.35	0.56		
С	0.20	0.36		
D	22.35	23.37		
E	7.62	8.26		
E1	6.09	7.12		
е	2.54 (TYP)			
eB		10.92		
L	2.92	3.81		

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